

2PC4617xMB series 50 V, 100 mA NPN general-purpose transistors Rev. 1 – 26 March 2012 P

Product data sheet

1. Product profile

1.1 General description

NPN general-purpose transistors in a leadless ultra small DFN1006B-3 (SOT883B) Surface-Mounted Device (SMD) plastic package.

Table 1. **Product overview**

Type number	Package	Package		
	NXP	JEITA	JEDEC	
2PC4617QMB	SOT883B	-	-	2PA1774QMB
2PC4617RMB	SOT883B	-	-	2PA1774RMB

1.2 Features and benefits

Leadless ultra small SMD plastic Power dissipation comparable to SOT23 package

AEC-Q101 qualified

Low package height of 0.37 mm

1.3 Applications

- General-purpose switching and amplification
- Mobile applications

1.4 Quick reference data

Parameter	Conditions	Min	Тур	Max	Unit
collector-emitter voltage	open base	-	-	50	V
collector current		-	-	100	mA
DC current gain	$V_{CE} = 6 \text{ V}; \text{ I}_{C} = 1 \text{ mA}$				
2PC4617QMB		120	-	270	
2PC4617RMB		180	-	390	
	collector-emitter voltage collector current DC current gain 2PC4617QMB	collector-emitter voltage collector currentopen baseDC current gain 2PC4617QMB $V_{CE} = 6 \text{ V}; I_C = 1 \text{ mA}$	collector-emitter voltageopen base-collector current-DC current gainV _{CE} = 6 V; I _C = 1 mA2PC4617QMB120	collector-emitter voltageopen base-collector currentDC current gainV _{CE} = 6 V; I _C = 1 mA-2PC4617QMB120 -	collector-emitter voltage open base - - 50 collector current - - 100 DC current gain V _{CE} = 6 V; I _C = 1 mA - 120 - 270



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2. Pinning information

Table 3.	Pinning		
Pin	Description	Simplified outline	Graphic symbol
1	base		
2	emitter		3
3	collector	2	1
		Transparent top view	2
			sym021

3. Ordering information

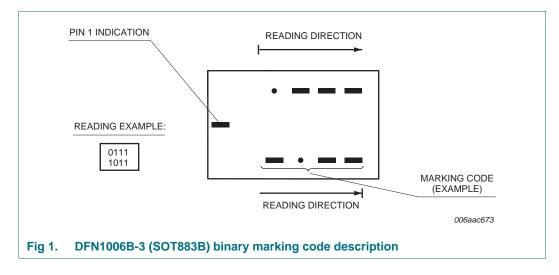
Table 4. Ordering	information		
Type number	Package		
	Name	Description	Version
2PC4617xMB series	DFN1006B-3	leadless ultra small plastic package; 3 solder lands; body $1.0 \times 0.6 \times 0.37$ mm	SOT883B

4. Marking

Table 5. Marking codes	
Type number	Marking code ^[1]
2PC4617QMB	0000 1111
2PC4617RMB	0001 0000

[1] For DFN1006B-3 (SOT883B) binary marking code description see Figure 1.

4.1 Binary marking code description



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5. Limiting values

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter		-	50	V
V _{CEO}	collector-emitter voltage	open base		-	50	V
V _{EBO}	emitter-base voltage	open collector		-	5	V
I _C	collector current			-	100	mA
I _{CM}	peak collector current	single pulse; $t_p \leq 1 \text{ ms}$		-	200	mA
I _{BM}	peak base current	single pulse; $t_p \leq 1 \text{ ms}$		-	100	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	[1][2]	-	250	mW
			[3][2]	-	590	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	+150	°C
T _{stg}	storage temperature			-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.

[3] Device mounted on an FR4 PCB, single-sided copper, mounting pad for collector 1 cm².

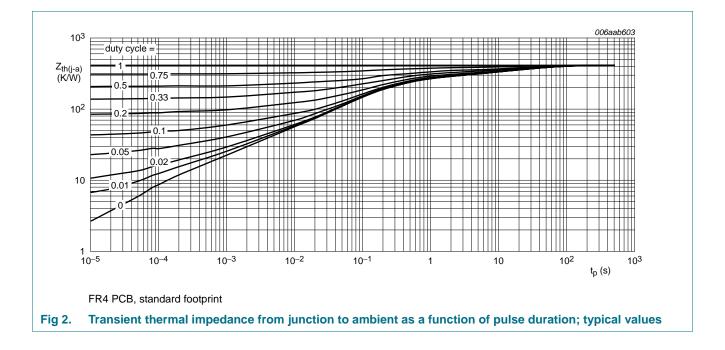
6. Thermal characteristics

Table 7.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from	in free air	<u>[1][2]</u> _	-	500	K/W
	junction to ambient		[3][2] _	-	212	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.

[3] Device mounted on an FR4 PCB, single-sided copper, mounting pad for collector 1 cm².



7. **Characteristics**

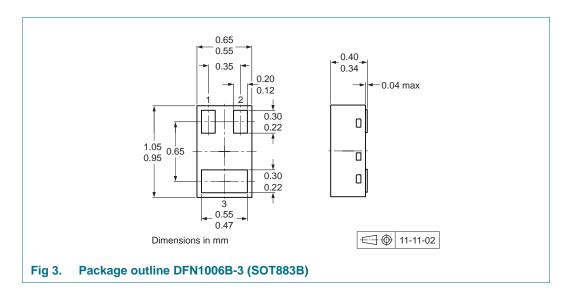
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
I _{CBO}	collector-base cut-off current	V_{CB} = 30 V; I _E = 0 A	-	-	100	nA
		$V_{CB} = 30 \text{ V}; \text{ I}_{E} = 0 \text{ A};$ T _j = 150 °C	-	-	5	μA
I _{EBO}	emitter-base cut-off current	$V_{EB} = 4 \text{ V}; I_C = 0 \text{ A}$	-	-	100	nA
h _{FE}	DC current gain	V _{CE} = 6 V; I _C = 1 mA				
	2PC4617QMB		120	-	270	
	2PC4617RMB		180	-	390	
V _{CEsat}	collector-emitter saturation voltage	$I_{\rm C} = 50$ mA; $I_{\rm B} = 5$ mA	[1] -	-	200	mV
f _T	transition frequency	$V_{CE} = 12 \text{ V}; \text{ I}_{C} = 2 \text{ mA};$ f = 100 MHz	100	-	-	MHz
C _c	collector capacitance	$V_{CB} = 12 \text{ V}; \text{ I}_{E} = \text{i}_{e} = 0 \text{ A};$ f = 1 MHz	-	-	1.5	pF

Test information 8.

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

Package outline 9.

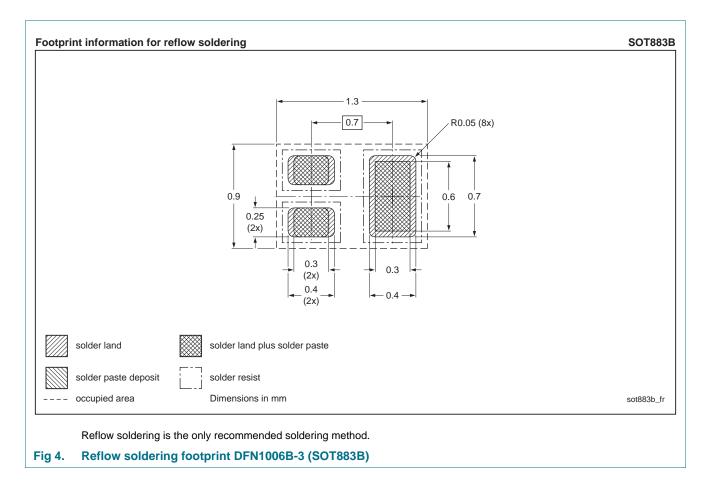


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10. Packing information

able 9. Packing The indicated -xxx and		digits of the 12NC ordering code.[1]	
Гуре number	Package	Description	Packing quantity 10000
2PC4617xMB series	DFN1006B-3 (SOT883B)	2 mm pitch, 8 mm tape and reel	-315
	(SOT883B)	ability of packing methods, see Section 14.	

11. Soldering



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12. Revision history

Table 10. Revision hist	ory			
Document ID	Release date	Data sheet status	Change notice	Supersedes
2PC4617XMB_SER v.1	20120326	Product data sheet	-	-

2PC4617XMB_SER

13. Legal information

13.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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